

## SANYO Semiconductors DATA SHEET

### N-Channel Silicon MOSFET 2SK3487—General-Purpose Switching Device **Applications**

#### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 2.5V drive.

### Specifications

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	١D		8	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	32	А
Allowable Power Dissipation	Da	Mounted on a ceramic board (250mm <sup>2</sup> ×0.8mm)	1.5	W
	PD	Tc=25°C	3.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	20			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =20V, V <sub>GS</sub> =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	VDS=10V, ID=4A	7.2	12		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on) 1	ID=4A, VGS=4V		25	33	mΩ
	R <sub>DS</sub> (on) 2	ID=2A, VGS=2.5V		33	47	mΩ
Input Capacitance	Ciss	VDS=10V, f=1MHz		1000		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		210		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =10V, f=1MHz		150		pF

Marking : LD

Continued on next page.

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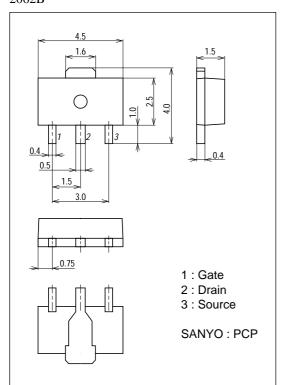
SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

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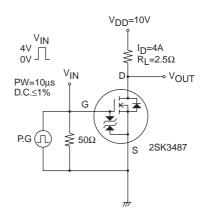
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		10		ns
Rise Time	tr	See specified Test Circuit.		60		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		27		ns
Fall Time	tf	See specified Test Circuit.		32		ns
Total Gate Charge	Qg	V <sub>DS</sub> =10V, V <sub>GS</sub> =4V, I <sub>D</sub> =8A		14		nC
Gate-to-Source Charge	Qgs	VDS=10V, VGS=4V, ID=8A		2.2		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =10V, V <sub>GS</sub> =4V, I <sub>D</sub> =8A		3.9		nC
Diode Forward Voltage	VSD	IS=8A, VGS=0		0.90	1.2	V

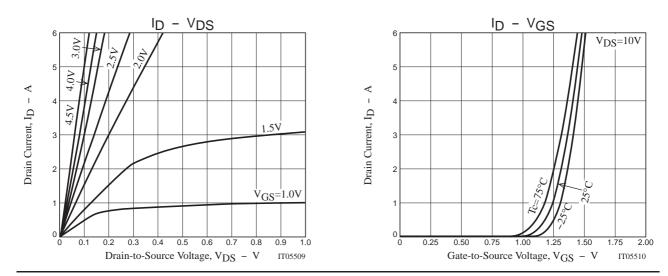
#### **Package Dimensions**

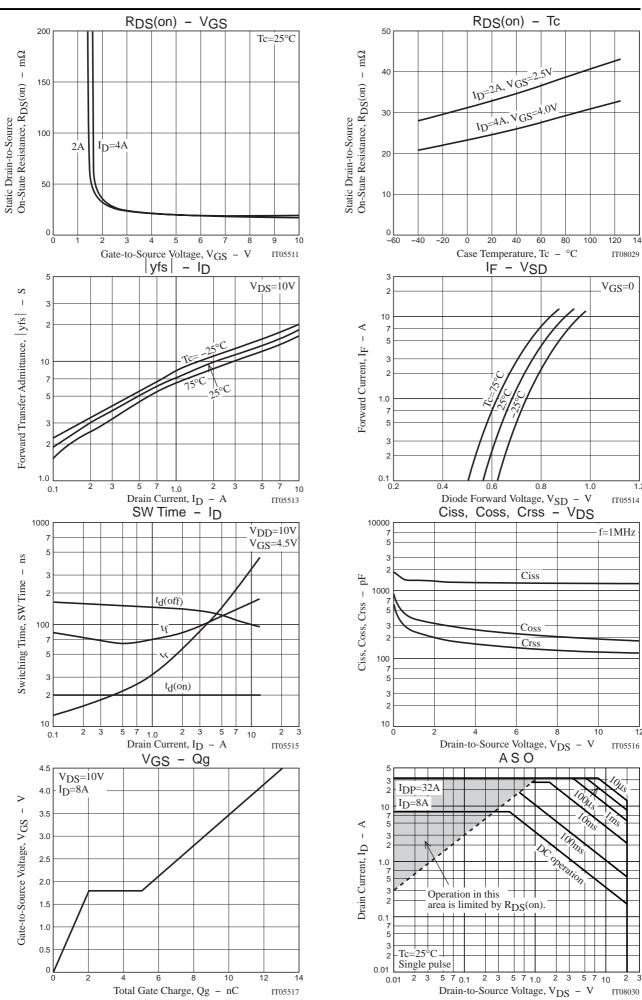
unit : mm 2062B



#### **Switching Time Test Circuit**





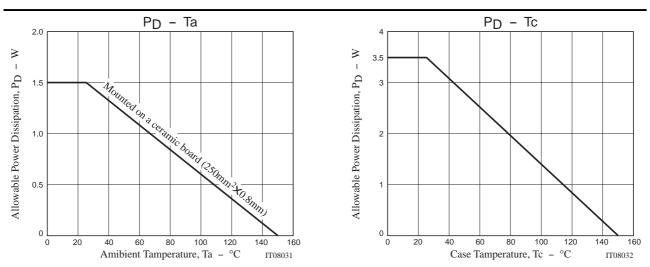


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# Note on usage : Since the 2SK3487 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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